





## Definitions

All specifications apply over a 5  $^{\circ}$ C to 40  $^{\circ}$ C range (unless otherwise stated) and 30 minutes after the instrument has been turned on.

### **Specification (spec.)**

Warranted performance. Specifications include guardbands to account for the expected statistical performance distribution, measurement uncertainties, and changes in performance due to environmental conditions.

Supplemental information is intended to provide information useful in applying the instrument, but that is not covered by the product warranty. The information is denoted as typical, or nominal.

### Typical (typ.)

Expected performance of an average unit which does not include guardbands. It is not covered by the product warranty.

### Nominal (nom.)

A general, descriptive term that does not imply a level of performance. It is not covered by the product warranty.

# Measurement Parameters and Range

## **Measurement parameters**

### Impedance parameters:

 $\begin{array}{l} |Z|, \ |Y|, L_s, L_p, C_s, C_p, R_s(R), R_p, X, G, B, D, Q, \theta_z, \\ \theta_y, \ |\Gamma|, \Gamma_x, \Gamma_y, \theta_\gamma \end{array}$ 

## Material parameters (option E4991A-002):

(see "Option E4991A-002 material measurement (typical)" on page 17) Permittivity parameters:  $|\varepsilon_r|, \varepsilon_r', \varepsilon_r'', \tan\delta$ Permeability parameters:  $|\mu_r|, \mu_r', \mu_r'', \tan\delta$ 

## **Measurement range**

Measurement range (|Z|): 130 m $\Omega$  to 20 k $\Omega$ . (Frequency= 1 MHz, Point averaging factor  $\geq 8$ , Oscillator level= -3 dBm; = -13 dBm; or = -23 dBm, Measurement accuracy  $\leq \pm 10\%$ , Calibration is performed within 23 °C  $\pm 5$  °C, Measurement is performed within  $\pm 5$  °C of calibration temperature)

## **Source Characteristics**

### Frequency

**Range:** 

 $1~\mathrm{MHz}$  to  $3~\mathrm{GHz}$ 

**Resolution:** 1 mHz

### Accuracy:

without Option E4991A-1D5: ±10 ppm (23 °C ±5 °C) ±20 ppm (5 °C to 40 °C) with Option E4991A-1D5: ±1 ppm (5 °C to 40 °C)

#### **Stability:**

with Option E4991A-1D5: ±0.5 ppm/year (5 °C to 40 °C)

### **Oscillator level**

### Range:

Power (when 50  $\Omega$  load is connected to test port): -40 dBm to 1 dBm (frequency  $\leq$  1 GHz) -40 dBm to 0 dBm (frequency > 1 GHz<sup>1</sup>) Current (when short is connected to test port): 0.0894 mArms to 10 mArms (frequency  $\leq$  1 GHz) 0.0894 mArms to 8.94 mArms (frequency > 1 GHz<sup>1</sup>) Voltage (when open is connected to test port): 4.47 mVrms to 502 mVrms (frequency  $\leq$  1 GHz) 4.47 mVrms to 447 mVrms (frequency > 1 GHz<sup>1</sup>)

### **Resolution:**

 $0.1 \ dB^2$ 

### Accuracy:

(Power, when 50  $\Omega$  load is connected to test port) Frequency  $\leq 1$  GHz:  $\pm 2$  dB (23 °C  $\pm 5$  °C)  $\pm 4$  dB (5 °C to 40 °C) Frequency > 1 GHz:  $\pm 3$  dB (23 °C  $\pm 5$  °C)  $\pm 5$  dB (5 °C to 40 °C) with Option E4991A-010: Frequency  $\leq 1$  GHz  $\pm 3.5$  dB (23 °C  $\pm 5$  °C)  $\pm 5.5$  dB (5 °C to 40 °C) Frequency > 1 GHz  $\pm 5.6$  dB (23 °C  $\pm 5$  °C)  $\pm 7.6$  dB (5 °C to 40 °C)

## Output impedance

#### **Output impedance:**

50  $\Omega$  (nominal)

## DC Bias (Option E4991A-001)

### **DC** voltage bias

Range:

0 to ±40 V

#### **Resolution:**

1 mV

#### Accuracy:

 $\pm \{0.1\% + 6 \text{ mV} + (\text{Idc}[\text{mA}] \ge 20 \Omega)[\text{mV}]\}$ (23 °C ±5 °C)

 $\pm \{0.2\% + 12 \text{ mV} + (\text{Idc}[\text{mA}] \times 40 \Omega)[\text{mV}]\}\$ (5 °C to 40 °C)

## **DC** current bias

#### **Range:**

100  $\mu A$  to 50 mA, –100  $\mu A$  to –50 mA

#### **Resolution**:

10 µA

#### Accuracy:

 $\begin{array}{l} \pm \{0.2\% + 20 \; \mu A + (Vdc[V]/10 \; k\Omega)[mA]\} \\ (23 \; ^{\circ}C \; \pm 5 \; ^{\circ}C) \\ \pm \{0.4\% + 40 \; \mu A + (Vdc[V]/5 \; k\Omega)[mA]\} \\ (5 \; ^{\circ}C \; to \; 40 \; ^{\circ}C) \end{array}$ 

## **DC** bias monitor

### **Monitor parameters:**

Voltage and current

### Voltage monitor accuracy:

 $\begin{array}{l} \pm \{0.5\% + 15 \ mV + (Idc[mA] \ x \ 2 \ \Omega)[mV]\} \\ (23 \ ^{\circ}C \ \pm 5 \ ^{\circ}C, \ typical) \\ \pm \{1.0\% + 30 \ mV + (Idc[mA] \ x \ 4 \ \Omega)[mV]\} \\ (5 \ ^{\circ}C \ to \ 40 \ ^{\circ}C, \ typical) \end{array}$ 

### Current monitor accuracy:

 $\pm \{0.5\% + 30 \mu A + (Vdc[V] / 40 k \Omega)[mA]\}$ (23 °C ±5 °C, typical)  $\pm \{1.0\% + 60 \mu A + (Vdc[V] / 20 k \Omega)[mA]\}$ (5 °C to 40 °C, typical)

<sup>1.</sup> It is possible to set more than 0 dBm (447 mV, 8.94 mA) oscillator level at frequency > 1 GHz. However, the characteristics at this setting are not guaranteed.

<sup>2.</sup> When the unit is set at mV or mA, the entered value is rounded to 0.1 dB resolution.

## Probe Station Connection Kit (Option E4991A-010)

## **Oscillator level**

 $\label{eq:power accuracy:} \begin{array}{l} \mbox{Frequency} \leq 1 \mbox{ GHz:} \\ \pm 5.5 \mbox{ dB} \ (5 \ ^{\circ}{\rm C} \ to \ 40 \ ^{\circ}{\rm C}) \\ \mbox{Frequency} > 1 \mbox{ GHz:} \\ \pm 7.6 \mbox{ dB} \ (5 \ ^{\circ}{\rm C} \ to \ 40 \ ^{\circ}{\rm C}) \end{array}$ 

## **Sweep Characteristics**

### Sweep conditions

### Sweep parameters:

Frequency, oscillator level (power, voltage, current), DC bias voltage, DC bias current

#### Sweep range setup:

Start/stop or center/span

#### Sweep types:

Frequency sweep: linear, log, segment Other parameters sweep: linear, log

#### Sweep mode:

Continuous, single

#### Sweep directions:

Oscillator level, DC bias (voltage and current): up sweep, down sweep Other parameters sweep: up sweep

other parameters sweep. up sweep

### Number of measurement points:

2 to 801

### **Delay time:**

Types: point delay, sweep delay, segment delay Range: 0 to 30 sec Resolution: 1 msec

### Segment sweep

#### Available setup parameters for each segment:

Sweep frequency range, number of measurement points, point averaging factor, oscillator level (power, voltage, or current), DC bias (voltage or current), DC bias limit (current limit for voltage bias, voltage limit for current bias)

### Number of segments:

1 to 16

#### Sweep span types:

Frequency base or order base

## **Measurement Accuracy**

## **Conditions for defining accuracy**

**Temperature:** 

 $23 \ ^{\circ}C \ \pm 5 \ ^{\circ}C$ 

Accuracy-specified plane: 7-mm connector of test head

Accuracy defined measurement points: Same points at which the calibration is done.

## Accuracy when open/short/load calibration is performed

Z ,  Y :	±(E <sub>a</sub> + E <sub>b</sub> ) [%] (see Figures 1 through 4 for examples of calculated accuracy)
θ:	$\pm \frac{(E_a + E_b)}{100}  [ \text{rad}]$
L, C, X, B:	$\pm (E_a + E_b) \ge \sqrt{(1 + D_x^2)} \ [\%]$
R, G:	$\pm \left(E_a + E_b\right) \ge \sqrt{\left(1 + Q_x^2\right)} \left[\%\right]$

**D:**  
at 
$$\left|D_x \tan\left[\frac{E_a + E_b}{100}\right]\right| < 1 \pm \frac{(1 + D_x^2) \tan\left[\frac{E_a + E_b}{100}\right]}{1 \mp D_x \tan\left[\frac{E_a + E_b}{100}\right]}$$

at 
$$D_x \leq 0.1$$

**Q**:

at

$$\pm \frac{E_a + E_b}{100}$$

 $\frac{E_a + E_b}{100}$ 

$$\left|Q_x \tan\left(\frac{E_a + E_b}{100}\right)\right| < 1 \quad \pm \frac{(1 + Q_x^2) \tan\left(\frac{E_a + E_b}{100}\right)}{1 \mp Q_x \tan\left(\frac{E_a + E_b}{100}\right)}$$

$$\text{at} \ \frac{10}{E_a+E_b} \geq Q_x \geq 10 \qquad \pm Q_x^2$$

## Accuracy when open/short/load/low-loss capacitor calibration is performed

$$|\mathbf{Z}|, |\mathbf{Y}|: \pm (E_a + E_b) [\%]$$

θ:

L, C, X, B: 
$$\pm \sqrt{(E_a + E_b)^2 + (E_c D_x)^2}$$
[%]

 $\pm \frac{E_c}{100}$  [rad]

**R**, **G**: 
$$\pm \sqrt{(E_a + E_b)^2 + (E_c Q_x)^2}$$
[%]

$$\begin{array}{l} \textbf{D:} \\ \text{at} \left| D_x \tan\left[\frac{E_c}{100}\right] \right| < 1 \pm \frac{(1 + D_x^2) \tan\left[\frac{E_c}{100}\right]}{1 \mp D_x \tan\left[\frac{E_c}{100}\right]} \end{array}$$

$$\begin{array}{l} \text{at } D_x \leq 0.1 & \pm \frac{E_c}{100} \\ \\ \textbf{0:} \\ \text{at } \left| Q_x \tan \left( \frac{E_c}{100} \right) \right| < 1 \pm \frac{(1 + Q_x^2) \tan \left( \frac{E_c}{100} \right)}{1 \mp Q_x \tan \left( \frac{E_c}{100} \right)} \end{array}$$

at 
$$\frac{10}{E_c} \ge Q_x \ge 10$$
  $\pm Q_x^2 \frac{E_c}{100}$ 

(See Figure 5)

### **Definition of each parameter**

**Dx** = Measurement value of D

 $\mathbf{Q}\mathbf{x}$  = Measurement value of Q

**Ea** = (Within  $\pm 5$  °C from the calibration temperature. Measurement accuracy applies when the calibration is performed at 23 °C  $\pm 5$  °C. When the calibration is performed beyond 23 °C  $\pm 5$  °C, measurement error doubles.)

```
at oscillator level ≥ -33 dBm:
±0.65 [%] (1 MHz ≤ Frequency ≤ 100 MHz)
±0.8 [%] (100 MHz < Frequency ≤ 500 MHz)
±1.2 [%] (500 MHz < Frequency ≤ 1 GHz)
±2.5 [%] (1 GHz < Frequency ≤ 1.8 GHz)
±5 [%] (1.8 GHz < Frequency ≤ 3 GHz)
```

at Oscillator level < -33 dBm:

±1 [%] (1 MHz ≤ Frequency ≤ 100 MHz) ±1.2 [%] (100 MHz < Frequency ≤ 500 MHz) ±1.2 [%] (500 MHz < Frequency ≤ 1 GHz) ±2.5 [%] (1 GHz < Frequency ≤ 1.8 GHz) ±5 [%] (1.8 GHz < Frequency ≤ 3 GHz)

$$\mathbf{Eb} = \pm \left[ \frac{Z_s}{|Z_x|} + Y_o \cdot |Z_x| \right] \times 100 \ [\%]$$

$$(|\mathbf{Zx}|: \text{ measurement value of } |\mathbf{Z}|)$$

$$\left[ 0.08 \times F \right]_{rest}$$

$$\mathbf{Ec} = \pm \left[ 0.06 + \frac{0.08 \times F}{1000} \right] [\%]$$

(F: frequency [MHz], typical)

**Zs** = (Within ±5 °C from the calibration temperature. Measurement accuracy applies when the calibration is performed at 23 °C ±5 °C. When the calibration is performed beyond 23 °C ±5 °C, the measurement accuracy decreases to half that described. F: frequency [MHz].)

at oscillator level = -3 dBm, -13 dBm, or -23 dBm:  $\pm (13 + 0.5 \times F) \text{ [m}\Omega \text{]}$  (averaging factor  $\ge 8$ )  $\pm (25 + 0.5 \times F) \text{ [m}\Omega \text{]}$  (averaging factor  $\le 7$ ) at oscillator level  $\ge -33 \text{ dBm}$   $\pm (25 + 0.5 \times F) \text{ [m}\Omega \text{]}$  (averaging factor  $\ge 8$ )  $\pm (50 + 0.5 \times F) \text{ [m}\Omega \text{]}$  (averaging factor  $\le 7$ ) at oscillator level < -33 dBm  $\pm (50 + 0.5 \times F) \text{ [m}\Omega \text{]}$  (averaging factor  $\ge 8$ )  $\pm (50 + 0.5 \times F) \text{ [m}\Omega \text{]}$  (averaging factor  $\ge 8$ )  $\pm (100 + 0.5 \times F) \text{ [m}\Omega \text{]}$  (averaging factor  $\ge 7$ )

**Yo =** (Within  $\pm 5$  °C from the calibration temperature. Measurement accuracy applies when the calibration is performed at 23 °C  $\pm 5$  °C. When the calibration is performed beyond 23 °C  $\pm 5$  °C, the measurement accuracy decreases to half that described. *F*: frequency [MHz].)

at oscillator level = -3 dBm, -13 dBm, -23 dBm:  $\pm(5 + 0.1 \times F) [\mu S]$  (averaging factor  $\ge 8$ )  $\pm(10 + 0.1 \times F) [\mu S]$  (averaging factor  $\le 7$ ) at oscillator level  $\ge -33 \text{ dBm}$ :  $\pm(10 + 0.1 \times F) [\mu S]$  (averaging factor  $\ge 8$ )  $\pm(30 + 0.1 \times F) [\mu S]$  (averaging factor  $\le 7$ ) at oscillator level < -33 dBm  $\pm(20 + 0.1 \times F) [\mu S]$  (averaging factor  $\ge 8$ )  $\pm(60 + 0.1 \times F) [\mu S]$  (averaging factor  $\ge 8$ )  $\pm(60 + 0.1 \times F) [\mu S]$  (averaging factor  $\le 7$ )

## **Measurement Accuracy**

(continued)

## Examples of calculated impedance measurement accuracy

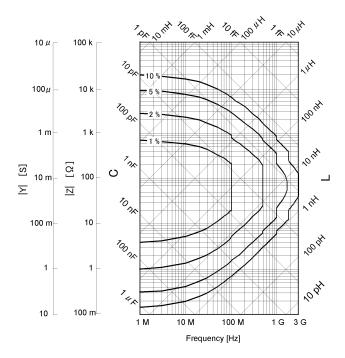


Figure 1. |Z|, |Y| Measurement accuracy when open/short/load calibration is performed. Oscillator level = -23 dBm, -13 dBm, -3 dBm. Point averaging factor ≥ 8 within ±5 °C from the calibration temperature.

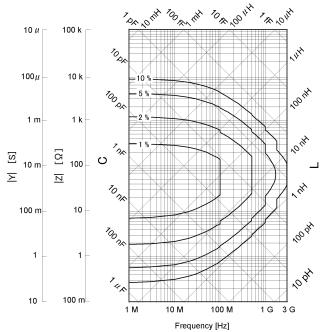


Figure 2. |Z|, |Y| Measurement accuracy when open/short/load calibration is performed. Oscillator level  $\geq$  –33 dBm. Point averaging factor  $\geq$  8 within ±5 °C from the calibration temperature.

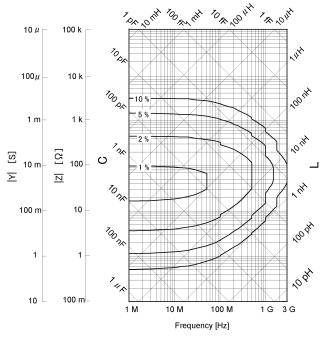


Figure 3. |Z|, |Y| Measurement accuracy when open/short/load calibration is performed. Oscillator level  $\geq$  –33 dBm. Point averaging factor  $\leq$  7 within ±5 °C from the calibration temperature.

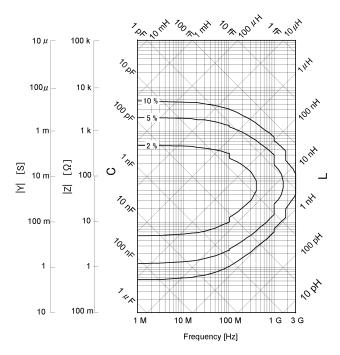


Figure 4. |Z|, |Y| Measurement accuracy when open/short/load calibration is performed. Oscillator level < -33 dBm within  $\pm$ 5 °C from the calibration temperature.

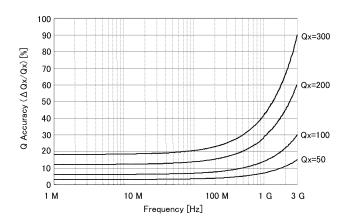


Figure 5. Q Measurement accuracy when open/short/load/low-loss capacitor calibration is performed (typical).

## Measurement Support Functions

## **Error correction**

#### Available calibration and compensation

Open/short/load calibration:

Connect open, short, and load standards to the desired reference plane and measure each kind of calibration data. The reference plane is called the calibration reference plane.

Low-loss capacitor calibration:

Connect the dedicated standard (low-loss capacitor) to the calibration reference plane and measure the calibration data.

Port extension compensation (fixture selection): When a device is connected to a terminal that is extended from the calibration reference plane, set the electrical length between the calibration plane and the device contact. Select the model number of the registered test fixtures in the E4991A's setup toolbar or enter the electrical length for the user's test fixture.

Open/short compensation:

When a device is connected to a terminal that is extended from the calibration reference plane, make open and/or short states at the device contact and measure each kind of compensation data.

#### Calibration/compensation data measurement point User-defined point mode:

Obtain calibration/compensation data at the same frequency and power points as used in actual device measurement, which are determined by the sweep setups. Each set of calibration/compensation data is applied to each measurement at the same point. If measurement points (frequency and/or power) are changed by altering the sweep setups, calibration/ compensation data become invalid and calibration or compensation data acquisition is again required.

## Measurement Support Functions (continued)

Fixed frequency and fixed power point mode:

Obtain calibration/compensation data at fixed frequency and power points covering the entire frequency and power range of the E4991A. In device measurement, calibration or compensation is applied to each measurement point by using interpolation. Even if the measurement points (frequency and/or power) are changed by altering the sweep setups, you don't need to retake the calibration or compensation data. Fixed frequency and user-defined power point mode:

Obtain calibration/compensation data at fixed frequency points covering the entire frequency range of the E4991A and at the same power points as used in actual device measurement which are determined by the sweep setups. Only if the power points are changed, calibration/ compensation data become invalid and calibration or compensation data acquisition is again required.

## Trigger

### Trigger mode:

Internal, external (external trigger input connector), bus (GPIB), manual (front key)

## Averaging

### Types:

Sweep-to-sweep averaging, point averaging

#### Setting range:

Sweep-to-sweep averaging: 1 to 999 (integer) Point averaging: 1 to 100 (integer)

## Display

### LCD display :

Type/size: color LCD, 8.4 inch (21.3 cm) Resolution: 640 (horizontal)  $\times$  480 (vertical)

#### Number of traces:

Data trace: 3 scalar traces + 2 complex traces (maximum) Memory trace: 3 scalar traces + 2 complex traces (maximum)

### Trace data math:

Data – memory, data/memory (for complex parameters), delta% (for scalar parameters), offset

### Format:

For scalar parameters: linear Y-axis, log Y-axis For complex parameters: Z, Y: polar, complex;  $\Gamma$ : polar, complex, Smith, admittance

#### Other display functions:

Split/overlay display (for scalar parameters), phase expansion

## Marker

### Number of markers:

Main marker: one for each trace (marker 1) Sub marker: seven for each trace (marker 2 to marker 8)

Reference marker: one for each trace (marker R)

### Marker search:

Search type: maximum, minimum, target, peak Search track: performs search with each sweep

**Other functions:** Marker continuous mode, marker coupled mode, marker list, marker statistics

## **Equivalent circuit analysis**

**Circuit models:** 3-component model (4 models), 4-component model (1 model)

### Analysis types:

Equivalent circuit parameters calculation, frequency characteristics simulation

## Limit marker test

Number of markers for limit test: 9 (marker R, marker 1 to 8)

**Setup parameters for each marker:** Stimulus value, upper limit, and lower limit

## **Mass storage**

**Built-in flexible disk drive:** 3.5 inch, 720 KByte or 1.44 MByte, DOS format

Hard disk drive:

2 GByte (minimum)

### Stored data:

State (binary), measurement data (binary, ASCII or CITI file), display graphics (bmp, jpg), VBA program (binary)

## Interface

## **GPIB**

**Standard conformity:** IEEE 488.1-1987, IEEE 488.2-1987

Available functions (function code)<sup>3</sup>: SH1, AH1, T6, TE0, L4, LE0, SR1, RL0, PP0, DT1, DC1, C0, E2

Numerical data transfer format: ASCII

Protocol: IEEE 488.2-1987

## **Printer parallel port**

Interface standard: IEEE 1284 Centronics

**Connector type:** 25-pin D-sub connector, female

## LAN interface

### Standard conformity:

10 Base-T or 100 Base-TX (automatically switched), Ethertwist, RJ45 connector

Protocol: TCP/IP

Functions:

## **USB** Port

Interface standard: USB 1.1

**Connector type:** Standard USB A, female

### Available functions:

Provides connection to printers and USB/GPIB Interface.

<sup>3.</sup> Refer to the standard for the meaning of each function code.

## Measurement Terminal (At Test Head)

**Connector type:** 

7-mm connector

## **Rear panel connectors**

## External reference signal input connector

Frequency: 10 MHz ±10 ppm (typical)

Level: 0 dBm to +6 dBm (typical)

Input impedance:  $50 \Omega$  (nominal)

**Connector type:** BNC, female

## Internal reference signal output connector

Frequency: 10 MHz (nominal)

Accuracy of frequency: Same as frequency accuracy described in *"Frequency"* on page 3

Level: +2 dBm (nominal)

**Output impedance:** 50  $\Omega$  (nominal)

**Connector type:** BNC, female

## High stability frequency reference output connector (Option E4991A-1D5)

Frequency: 10 MHz (nominal)

### Accuracy of frequency:

Same as frequency accuracy described in *"Frequency"* on page 3

Level:

+2 dBm (nominal)

**Output impedance:** 50  $\Omega$  (nominal)

**Connector type:** BNC, female

## **External trigger input connector**

#### Level:

LOW threshold voltage:  $0.5~\rm V$  HIGH threshold voltage:  $2.1~\rm V$  lnput level range:  $0~\rm V$  to +5  $\rm V$ 

### Pulse width (Tp):

 $\geq 2 \,\mu sec$  (typical). See Figure 6 for definition of Tp.

### Polarity:

Positive or negative (selective)

#### **Connector type:**

BNC, female

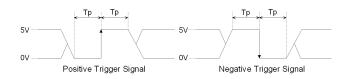


Figure 6. Definition of pulse width (Tp)

## **General Characteristics**

## **Environment conditions**

## **Operating condition**

**Temperature:** 5 °C to 40 °C

#### **Humidity**:

(at wet bulb temperature  $\leq 29$  °C, without condensation) Flexible disk drive non-operating condition: 15% to 90% RH Flexible disk drive operating condition: 20% to 80% RH

#### Altitude:

0 m to 2,000 m (0 feet to 6,561 feet)

Vibration:

0.5 G maximum, 5 Hz to 500 Hz

Warm-up time: 30 minutes

#### Non-operating storage condition

#### Temperature:

–20 °C to +60 °C

#### **Humidity**:

(at wet bulb temperature ≤ 45 °C, without condensation) 15% to 90% RH

#### Altitude:

0 m to 4,572 m (0 feet to 15,000 feet)

#### Vibration:

1 G maximum, 5 Hz to 500 Hz

## **General Characteristics**

(continued)

## **Other specifications**

## EMC

European Council Directive 89/336/EEC

## **CE** ISM 1-A

IEC 61326-1:1997+A1 CISPR 11:1990 / EN 55011:1991 Group 1, Class A IEC 61000-4-2:1995 / EN 61000-4-2:1995 4 kV CD / 4 kV AD IEC 61000-4-3:1995 / EN 61000-4-3:1996 3 V/m, 80-1000 MHz, 80% AM IEC 61000-4-4:1995 / EN 61000-4-4:1995 1 kV power / 0.5 kV Signal IEC 61000-4-5:1995 / EN 61000-4-5:1995 0.5 kV Normal / 1 kV Common IEC 61000-4-6:1996 / EN 61000-4-6:1996 3 V, 0.15-80 MHz, 80% AM IEC 61000-4-11:1994 / EN 61000-4-11:1994 100% 1cycle **Note:** When tested at 3 V/m according to

**Note:** When tested at 3 V/m according to EN 61000-4-3:1996, the measurement accuracy will be within specifications over the full immunity test frequency range of 80 MHz to 1000 MHz except when the analyzer frequency is identical to the transmitted interference signal test frequency.

## **N10149**

AS/NZS 2064.1/2 Group 1, Class A

## Safety

## **CE** ISM 1-A

European Council Directive 73/23/EEC IEC 61010-1:1990+A1+A2 / EN 61010-1:1993+A2 INSTALLATION CATEGORY II, POLLUTION DEGREE 2 INDOOR USE IEC60825-1:1994 CLASS 1 LED PRODUCT



## LR95111C

CAN/CSA C22.2 No. 1010.1-92

## **Power requirements**

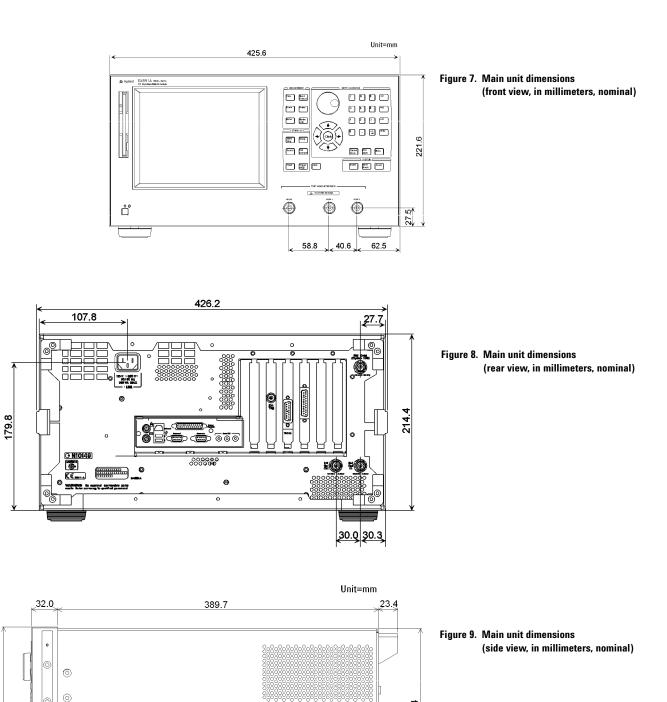
90~V to  $132~V\!,$  or 198~V to 264~V (automatically switched), 47~Hz to  $63~Hz,~350~V\!A$  maximum

## Weight

Main unit: 17 kg (nominal) Test head: 1 kg (nominal)

## Dimensions

Main unit: See Figure 7 through Figure 9 Test head: See Figure 10 Option E4991A-007 test head dimensions: See Figure 11 Option E4991A-010 test head dimensions: See Figure 12



221.6

12.8

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21.0

0

0

214.4

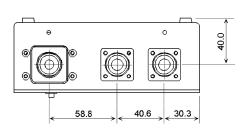
18.0

©

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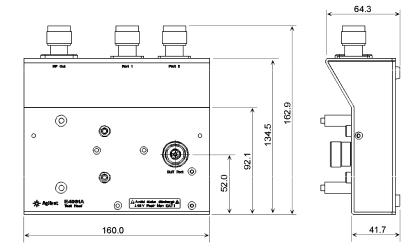
17.3

## **General Characteristics** (continued)



Unit=mm

Figure 10. Test head dimensions (in millimeters, nominal)



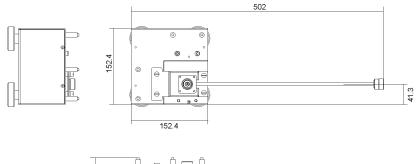
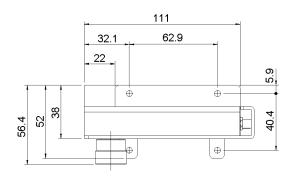




Figure 11. Option E4991A-007 test head dimensions (in millimeters,nominal)

## General Characteristics (continued)



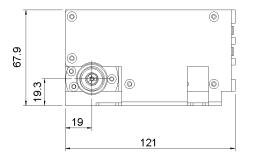


Figure 12. Option E4991A-010 test head dimensions (in millimeters,nominal)

## **Furnished accessories**

Model/option number	Description	Quantity
Agilent E4991A	Agilent E4991A impedance/material analyzer (main unit)	1
•	Test head	1
	Agilent 16195B 7-mm calibration kit	1
	Torque wrench	1
	E4991A recovery disk	1
	Power cable	1
	CD-ROM (English/Japanese PDF manuals)₄	1

4. The CD-ROM includes an operation manual, an installation and quick start guide, and a programming manual. A service manual is not included.

## Option E4491A-002 Material Measurement (Typical)

## **Measurement parameter**

Permittivity parameters:  $|\varepsilon_r|, \varepsilon_r', \varepsilon_r'', \tan\delta$ 

Permeability parameters:  $|\mu_r|, \mu_r', \mu_r'', \tan\delta$ 

## **Frequency range**

Using with Agilent 16453A: 1 MHz to 1 GHz (typical)

## Using with Agilent 16454A:

1 MHz to 1 GHz (typical)

## **Measurement accuracy**

## Conditions for defining accuracy:

Calibration:

Open, short, and load calibration at the test port (7-mm connector)

Calibration temperature:

Calibration is performed at an environmental temperature within the range of 23 °C ± 5 °C. Measurement error doubles when calibration temperature is below 18 °C or above 28 °C. Temperature:

Temperature deviation: within  $\pm 5$  °C from the calibration temperature

Environment temperature: Measurement accuracy applies when the calibration is performed at 23 °C  $\pm$ 5 °C. When the calibration is below

18 °C or above 23 °C, measurement error doubles. Measurement frequency points:

Same as calibration points

Oscillator level:

Same as the level set at calibraiton

Point averaging factor:  $\geq 8$ 

Electrode pressure setting of 16453A: maximum

### Typical accuracy of permittivity parameters:

$$\varepsilon_{r}' \operatorname{accuracy} \left[ = \frac{\Delta \varepsilon'_{rm}}{\varepsilon'_{rm}} \right]:$$

$$\pm \left[ 5 + \left[ 10 + \frac{0.1}{f} \right] \frac{t}{\varepsilon'_{rm}} + 0.25 \frac{\varepsilon'_{rm}}{t} + \frac{100}{\left| 1 - \left[ \frac{13}{f \sqrt{\varepsilon'_{rm}}} \right]^2 \right|} \right] [\%]$$
(at tan  $\delta < 0.1$ )

Loss tangent accuracy of  $\dot{\varepsilon}_r$  (=  $\Delta \tan \delta$ ): ±( $E_a + E_b$ ) (at tan $\delta < 0.1$ )

where,

 $E_{\mathrm{a}}$ 

at Frequency  $\leq 1$  GHz:

$$0.002 + \frac{0.001}{f} \cdot \frac{t}{\varepsilon'_{rm}} + 0.004f + \frac{0.1}{\left|1 - \left(\frac{13}{f\sqrt{\varepsilon'_{rm}}}\right)^2\right|}$$

$$E_b = \left[ \frac{\Delta \varepsilon'_{rm}}{\varepsilon'_{rm}} \cdot \frac{1}{100} + \varepsilon'_{rm} \frac{0.002}{t} \right] \tan \delta$$

*f* = Measurement frequency [GHz]

t = Thickness of MUT (material under test) [mm]

 $\epsilon'_{rm}$  = Measured value of  $\epsilon'_r$ 

 $tan\delta$  = Measured value of dielectric loss tangent

#### Typical accuracy of permeability parameters:

 $\mu_r'$  accuracy  $\begin{bmatrix} \Delta \mu'_{rm} \end{bmatrix}$ 

$$\left[=\frac{-r}{\mu'_{rm}}\right]:$$

$$4 + \frac{0.02}{f} \times \frac{25}{F\mu'_{rm}} + F\mu'_{rm} \left[1 + \frac{15}{F\mu'_{rm}}\right]^2 f^2 [\%]$$

$$\tan\delta$$

(at tar <0.1)

Loss tangent accuracy of  $\dot{\mu}_r$  (=  $\Delta tan\delta$ ): ±( $E_a$  +  $E_b$ ) (at tan $\delta$  <0.1)

where,

$$E_{a} = \frac{0.002 + \frac{0.001}{F\mu'_{rm}f} + 0.004f}{E_{b}}$$
$$E_{b} = \frac{\Delta\mu_{rm}'}{\mu'_{rm}} \cdot \frac{\tan\delta}{100}$$

*f* = Measurement frequency [GHz]

$$F = h \ln \frac{c}{b} [mm]$$

- *h* = Height of MUT (material under test) [mm]
- *b* = Inner diameter of MUT (material under test) [mm]
- c = Outer diameter of MUT (material under test) [mm]

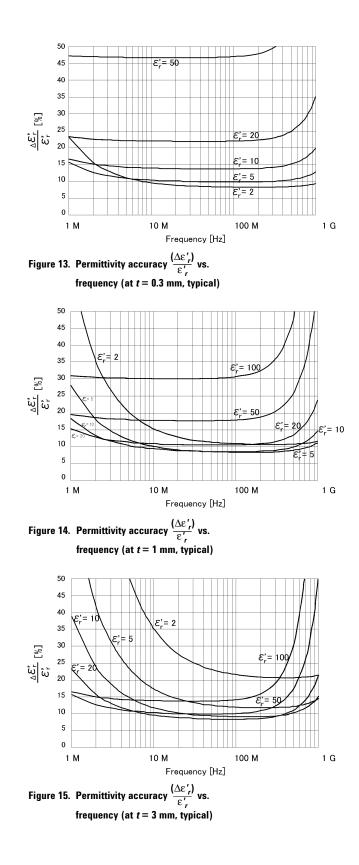
 $\mu'_{rm}$  = Measured value of  $\mu'_r$ 

 $tan\delta$  = Measured value of loss tangent

## **Option E4491A-002 Material Measurement (typical)**

(continued)

Examples of calculated permittivity measurement accuracy



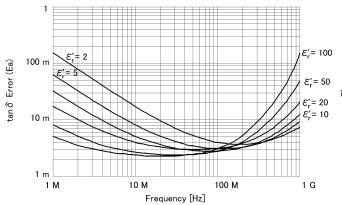
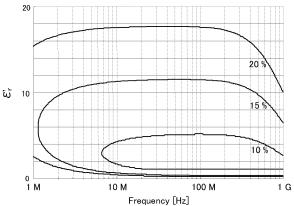


Figure 16. Dielectric loss tangent  $(tan\delta)$ accuracy vs. frequency (at t = 0.3 mm, typical)<sup>8</sup>



20

15 %

10 %

1 G

100 M

Figure 19. Permittivity ( $\varepsilon'_r$ ) vs. frequency (at t = 0.3 mm, typical)

60

50

40

30

20

10

0

1 M

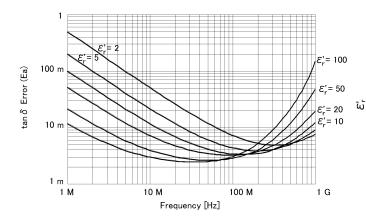
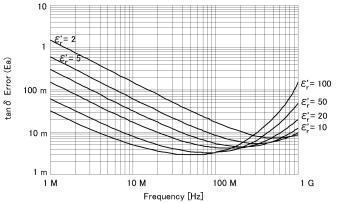


Figure 17. Dielectric loss tangent (tan $\delta$ ) accuracy vs. frequency (at t = 1 mm, typical)<sup>8</sup>



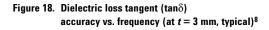


Figure 20. Permittivity  $(\epsilon'_r)$  vs. frequency (at t = 1 mm, typical)

10 M

Frequency [Hz]

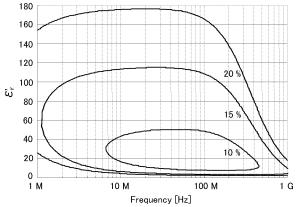


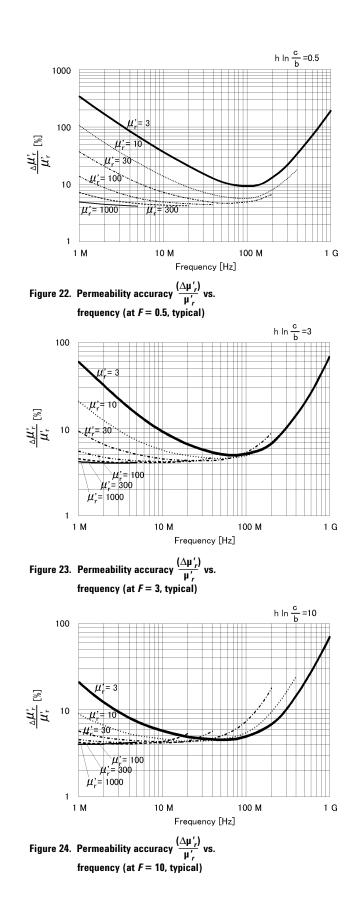
Figure 21. Permittivity ( $\epsilon'_r$ ) vs. frequency (at t = 3 mm, typical)

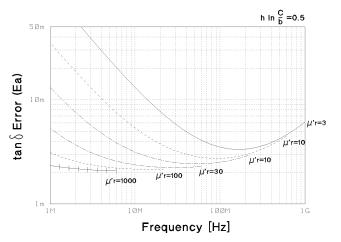
<sup>8.</sup> This graph shows only frequency dependence of  $E_a$  to simplify it. The typical accuracy of tan $\delta$  is defined as  $E_a + E_{b'}$  refer to "Typical accuracy of permittivity parameters" on page 17.

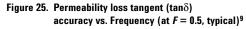
## **Option E4991A-002 Material Measurement (typical)**

(continued)

Examples of calculated permeability measurement accuracy







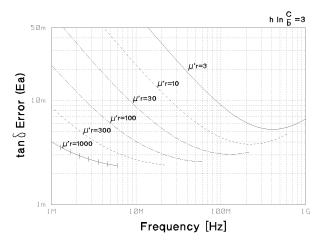


Figure 26. Permeability loss tangent  $(tan \delta)$ accuracy vs. frequency (at F = 3, typical)<sup>9</sup>

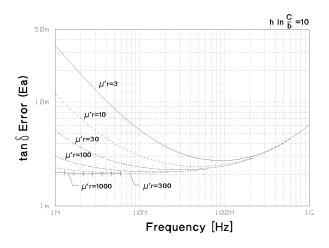
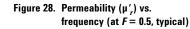


Figure 27. Permeability loss tangent  $(tan\delta)$ accuracy vs. frequency (at F = 10, typical)<sup>9</sup>

h In  $\frac{c}{b}$  =0.5 1k 900 800 700 600 5% 10% 20% μ, 500 400 300 200 100 0 1 M 10 M 100 M 1 G Frequency [Hz]



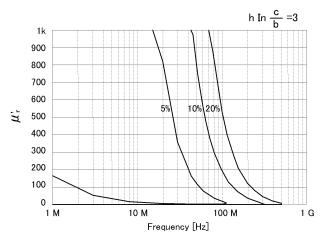


Figure 29. Permeability  $(\mu'_r)$  vs. frequency (at F = 3, typical)

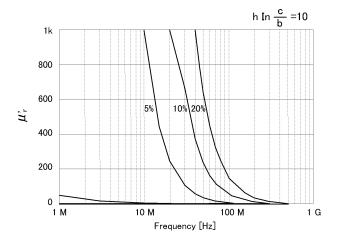


Figure 30. Permeability  $(\mu'_r)$  vs. frequency (at F = 10, typical)

This graph shows only frequency dependence of E<sub>a</sub> to simplify it. The typical accuracy of tanδ is defined as E<sub>a</sub> + E<sub>b</sub>, refer to "Typical accuracy of permeability parameters" on page 18.

## **Option E4991A-007 Temperature Characteristic Test Kit**

This section contains specifications and supplemental information for the E4991A Option E4991A-007. Except for the contents in this section, the E4991A standard specifications and supplemental information are applied.

## **Operation temperature**

### Range:

-55 °C to +150 °C (at the test port of the high temperature cable)

## **Source characteristics**

## Frequency

Range: 1 MHz to 3 GHz

## **Oscillator level**

Source power accuracy at the test port of the high temperature cable:

Frequency ≤ 1 GHz: +2 dB/-4 dB (23 °C ±5 °C) +4 dB/-6 dB (5 °C to 40 °C) Frequency > 1 GHz: +3 dB/-6 dB (23 °C ±5 °C) +5 dB/-8 dB (5 °C to 40 °C)

## Measurement accuracy (at 23 °C ±5 °C)

## Conditions<sup>10</sup>

### The measurement accuracy is specified when the following conditions are met:

- Calibration: open, short and load calibration is completed at the test port (7-mm connector) of the high temperature cable
- Calibration temperature: calibration is performed at an environmental temperature within the range of 23 °C  $\pm$ 5 °C. Measurement error doubles when calibration temperature is below 18 °C or above 28 °C.
- Measurement temperature range: within  $\pm 5$  °C of calibration temperature

Measurement plane: same as calibration plane Oscillator level: same as the level set at calibration

### Impedance, admittance and phase angle accuracy:

$$\begin{array}{ll} |\mathbf{Z}|,\,|\mathbf{Y}| & \pm (E_a + E_b \,)\,[\%] \\ & (\text{see Figure 31 through Figure 34 for calculated accuracy}) \end{array}$$

 $\pm \frac{(E_a + E_b)}{100} \text{ [rad]}$ 

where,

θ

$$\begin{split} E_a &= \text{at oscillator level} \geq -33 \text{ dBm:} \\ &\pm 0.8 \ [\%] \ (1 \text{ MHz} \leq f \leq 100 \text{ MHz}) \\ &\pm 1 \ [\%] \ (100 \text{ MHz} < f \leq 500 \text{ MHz}) \\ &\pm 1.2 \ [\%] \ (500 \text{ MHz} < f \leq 1 \text{ GHz}) \\ &\pm 2.5 \ [\%] \ (1 \text{ GHz} < f \leq 1.8 \text{ GHz}) \\ &\pm 5 \ [\%] \ (1.8 \text{ GHz} < f \leq 3 \text{ GHz}) \end{split}$$

at oscillator level  $\geq -33$  dBm: ±1.2 [%] (1 MHz  $\leq f \leq 100$  MHz) ±1.5 [%] (100 MHz  $< f \leq 500$  MHz) ±1.5 [%] (500 MHz  $< f \leq 1$  GHz) ±2.5 [%] (1 GHz  $< f \leq 1.8$  GHz) ±5 [%] (1.8 GHz  $< f \leq 3$  GHz) (Where, f is frequency)

$$E_b = \pm \left( \frac{Z_s}{|Z_x|} + Y_o \times |Z_x| \right) \times 100^{[\%]}$$

Where,

 $|Z_x|$  = Absolute value of impedance

- $Z_s = \text{At oscillator level} = -3 \text{ dBm}, -13 \text{ dBm}, \text{ or } -23 \text{ dBm}:$   $\pm (30 + 0.5 \times F) \text{ [m}\Omega\text{] (point averaging factor} \ge 8)$   $\pm (40 + 0.5 \times F) \text{ [m}\Omega\text{] (point averaging factor} \le 7)$ 
  - At oscillator level  $\geq -33$  dBm:  $\pm (35 + 0.5 \times F) [m\Omega]$  (point averaging factor  $\geq 8$ )  $\pm (70 + 0.5 \times F) [m\Omega]$  (point averaging factor  $\leq 7$ )
  - At oscillator level < -33 dBm:  $\pm (50 + 0.5 \times F) [m\Omega]$  (point averaging factor  $\ge 8$ )  $\pm (150 + 0.5 \times F) [m\Omega]$  (point averaging factor  $\le 7$ )

(Where, F is frequency in MHz)

- $\begin{array}{l} Y_o &= \text{At oscillator level} = -3 \text{ dBm}, \ -13 \text{ dBm}, \ -23 \text{ dBm}: \\ &\pm (12 \pm 0.1 \times F) \ [\mu\text{S}] \ (\text{point averaging factor} \geq 8) \\ &\pm (20 \pm 0.1 \times F) \ [\mu\text{S}] \ (\text{point averaging factor} \leq 7) \end{array}$ 
  - At oscillator level  $\geq -33$  dBm:  $\pm (15 + 0.1 \times F) [\mu S]$  (point averaging factor  $\geq 8$ )  $\pm (40 + 0.1 \times F) [\mu S]$  (point averaging factor  $\leq 7$ )

At oscillator level < -33 dBm:

 $\pm \left(35 + 0.1 \times F\right) \left[\mu S\right]$  (point averaging factor  $\geq 8)$ 

 $\pm \left(80 + 0.1 \times F\right) \left[\mu S\right]$  (point averaging factor  $\leq 7)$ 

(Where, F is frequency in MHz)

10. The high temperature cable must be kept at the same position throughout calibration and measurement.

## Calculated Impedance/ Admittance Measurement Accuracy

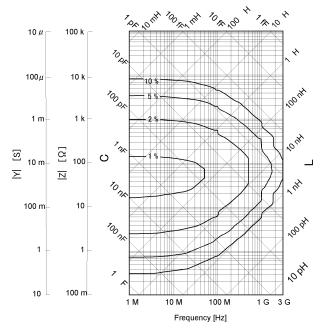


Figure 31. |Z|, |Y| measurement accuracy when open/short/load calibration is performed. Oscillator level = −23 dBm, −13 dBm, −3 dBm. Point averaging factor ≥ 8 within ±5 °C of calibration temperature.

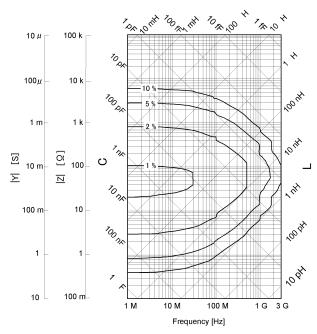


Figure 32. |Z|, |Y| measurement accuracy when open/short/load calibration is performed. Oscillator level ≥ -33 dBm. Point averaging factor ≥ 8 within ±5 °C of calibration temperature.

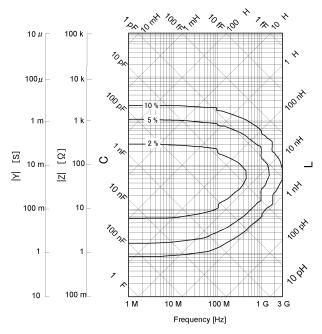


Figure 33. |Z|, |Y| measurement accuracy when open/short/load calibration is perfomed. Oscillator level  $\geq$  -33 dBm. Point averaging factor  $\leq$  7 within ±5 °C of calibration temperature.

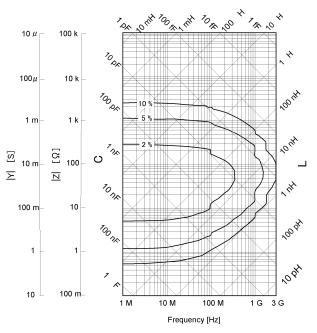


Figure 34. |Z|, |Y| measurement accuracy when open/short/load calibration is performed. Oscillator level < −33 dBm. Point averaging factor ≥ 8 within ±5 °C of calibration temperature.

## Typical Effects of Temperature Change on Measuement Accuracy

When the temperature at the test port (7-mm connector) of the high temperature cable changes from the calibration temperature, typical measurement accuracy involving temperature dependence effects (errors) is applied. The typical measurement accuracy is represented by the sum of error due to temperature coefficients  $(E_a, Y_o and Z_s)$ , hysteresis error  $(E_{ah}, Y_{oh})$  and  $Z_{sh}$  and the specified accuracy.

## Conditions

The typical measurement accuracy is applied when the following conditions are met:

## Conditions of $E_a'$ , $Z_s'$ and $Y_o'$ :

Measurement temperature: -55 °C to 5 °C or 40 °C to 150 °C at test port. For 5 °C to 40 °C,  $E_a$ ,  $Y_o$  and  $Z_s$  are 0 (neglected). Temperature change:  $\geq 5$  °C from calibration temperature when the temperature compensation is off.  $\geq 20$  °C from calibration temperature when the temperature compensation is set to on. Calibration temperature: 23 °C ±5 °C Calibration mode: user calibration Temperature compensation: temperature compensation data is acquired at the same temperature points as measurement temperatures.

## Conditions of $E_{ah}$ , $Z_{sh}$ and $Y_{oh}$ :

Measurement temperature: -55 °C to 150 °C at the test port Calibration temperature: 23 °C ±5 °C Calibration mode: user calibration Typical measurement accuracy (involving temperature dependence effects)<sup>11</sup>:

$$|Z|, |Y|: \pm (E_a + E_b + E_c + E_d) [\%]$$
  

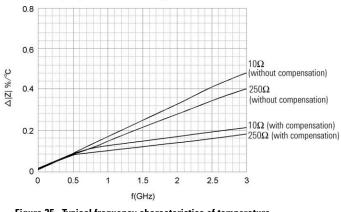
$$\theta \qquad : \pm \frac{(E_a + E_b + E_c + E_d)}{100} [rad]$$

Where,

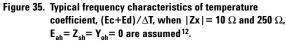
$$\begin{split} E_c &= E_a \times \Delta T + E_{ah} \\ E_d &= \pm \bigg[ \frac{Z_s \times \Delta T + Z_{sh}}{|Z_x|} + (Y_o \times \Delta T + Y_{oh}) \times |Z_x| \times \bigg] 100 \, [\%] \end{split}$$

Where,

 $|Z_x|$  = Absolute value of measured impedance



Typical frequency characteristics of temperature coefficient



Here, <i>I</i>	Ξ1.	$Z^{\prime}$	and	Ύ	are	given	bv	the	following	equations:
11010, 1	a,	2 s	ana	10	arc	Stron	$\nu_{J}$	unc	10110 millig	equations.

	Without temperature compensation	With temperature compensation				
		$1~{\rm MHz} \le f < 500~{\rm MHz}$	500 MHz $\leq f \leq 3$ GHz			
Ea	$0.006 + 0.015 \times f$ [%/°C]	$0.006 + 0.015 \times f$ [%/°C]	$0.006 + 0.015 \times f [\%/^{\circ}C]$			
$Z_s$	$1 + 10 \times f [\mathrm{m}\Omega/^{\circ}\mathrm{C}]$	$1 + 10 \times f [\text{m}\Omega/^{\circ}\text{C}]$	$5 + 2 \times f [m\Omega/^{\circ}C]$			
Y	$0.3 + 3 \times f [\mu S/^{\circ}C]$	$0.3 + 3 \times f [\mu S/^{\circ}C]$	$1.5 + 0.6 \times f  [\mu S/^{\circ}C]$			

f = Measurement frequency in GHz

 $E_{ah}$ ,  $Z_{sh}$  and  $Y_{oh}$  are given by following equations:

$$E_{ah} = E_a \times \Delta T_{max} \times 0.3 \ [\%]$$

$$Z_{sh} = Z_s \times \Delta T_{max} \times 0.3 \,[\,\mathrm{m}\Omega\,]$$

$$Y_{oh} = Y_o \times \Delta T_{max} \times 0.3 \ [\mu S]$$

 $\Delta T$  = Difference of measurement temperature from calibration temperature

 $\Delta T_{max}$  = Maximum temperature change (°C) at the test port from calibration temperature after the calibration is performed.

<sup>11.</sup> See graphs in Figure 35 for the calculated values of (Ec+Ed) exclusive of the hysteresis errors  $E_{eh^*} \, Z_{sh}$  and  $_{Yoh^*}$  when measured impedance is 10  $\Omega$  and 250  $\Omega.$ 

<sup>12.</sup> Read the value of  $\Delta |Z| \%^{\circ}C$  at the material measurement frequency and multiply it by  $\Delta T$  to derive the value of (Ec+Ed) when  $E_{ah} = Y_{oh} = Z_{sh} = 0$ .

## Typical Material Measurement Accuracy When Using Options E4991A-002 and E4991A-007

Material measurement accuracy contains the permittivity and permeability measurement accuracy when the E4991A with Option E4991A-002 and E4991A-007 is used with the 16453A or 16454A test fixture.

#### **Measurement parameter**

### Permittivity parameters:

 $|\varepsilon_r|, \varepsilon'_r, \varepsilon'', \tan\delta$ 

Permeability parameters:  $|\mu_r|, \mu'_r, \mu'', \tan\delta$ 

### Frequency

Use with Agilent 16453A: 1 MHz to 1 GHz (typical)

Use with Agilent 16454A: 1 MHz to 1 GHz (typical)

### **Opertation temperature**

**Range:** 

-55 °C to +150 °C (at the test port of the high temperature cable)

## Typical material measurement accuracy (at 23 °C ±150 °C)

#### Conditions

#### The measurement accuracy is specified when the following conditions are met:

Calibration: Open, short and load calibration is completed at the test port (7-mm connector) of the high temperature cable

Calibration temperature: Calibration is performed at an environmental temperature within the range of 23 °C  $\pm$ 5 °C. Measurement error doubles when calibration temperature is below 18 °C or above 28 °C.

- Measurement temperature range: Within  $\pm 5~^\circ\mathrm{C}$  of calibration temperature
- Measurement frequency points: Same as calibration points (User Cal)

Oscillator level: Same as the level set at calibration Point averaging factor:  $\geq 8$ 

Typical permittivity measurement accuracy<sup>13</sup>:

$$\varepsilon_r$$
 accuracy

$$\pm \left[ 5 + \left[ 10 + \frac{0.5}{f} \right] \times \frac{t}{\hat{\epsilon}_{rm}} + 0.25 \times \frac{\hat{\epsilon}_{rm}}{t} + \frac{100}{\left| 1 - \left[ \frac{13}{f \sqrt{\hat{\epsilon}_{rm}}} \right]^2 \right|} \right]$$

 $\left[E_{\varepsilon} = \frac{\Delta \varepsilon'_{rm}}{\varepsilon'}\right]:$ 

[%] (at  $tan\delta < 0.1$ )

Loss tangent accuracy of  $\dot{\epsilon}_r$  (=  $\Delta tan \delta$ ) :

 $\pm (E_a + E_b)$  (at tan $\delta < 0.1$ )

where,

$$E_a$$
 =

at Frequency  $\leq 1 \text{ GHz}$ 

$$0.002 + \frac{0.0025}{f} \times \frac{t}{\epsilon'_{rm}} + (0.008 \times f) + \frac{0.1}{\left|1 - \left(\frac{13}{f \sqrt{\epsilon'_{rm}}}\right)^2\right|}$$

$$E_b = \left(\frac{\Delta \varepsilon_{rm}}{\varepsilon_{rm}} \times \frac{1}{100} + \varepsilon_{rm} \frac{0.002}{t}\right) \times \tan\delta$$

f = Measurement frequency [GHz]

*t* = Thickness of MUT (material under test) [mm]

 $\varepsilon'_{rm}$  = Measured value of  $\varepsilon'_r$ 

 $tan\delta$  = Measured value of dielectric loss tangent

<sup>13.</sup> The accuracy applies when the electrode pressure of the 16453A is set to maximum.

### Typical permeability measurement accuracy :

$$\mu_r$$
 accuracy

Accuracy 
$$E_{\mu} = \left(\frac{\Delta \mu'_{rm}}{\mu'_{rm}}\right):$$

$$4 + \frac{0.02}{f} \times \frac{25}{F \times \mu'_{rm}} + F \times \mu'_{rm} \times \left[1 + \frac{15}{F \times \mu'_{rm}}\right]^2 \times f^2$$

[%] (at  $tan\delta < 0.1$ )

Loss tangent accuracy of  $\dot{\mu}_r$  (=  $\Delta tan\delta$ ) :

$$\pm (E_a + E_b)$$
 (at tan $\delta < 0.1$ )

where,

$$E_a = 0.002 + \frac{0.005}{F \times \mu'_{rm} \times f} + 0.004 \times f$$

$$E_b = \frac{\Delta \mu_{rm}}{\mu_{rm}} \times \frac{\tan \delta}{100}$$

f= Measurement frequency [GHz]

$$F = h \ln \frac{c}{b} [mm]$$

h= Height of MUT (material under test) [mm]

- b= Inner diameter of MUT [mm]
- c= Outer diameter of MUT [mm]
- $\mu'_{rm}$  = Measured value of  $\mu'_{r}$
- $tan\delta$  = Measured value of loss tangent

## **Examples of Calculated Permittivity Measurement** Accuracy

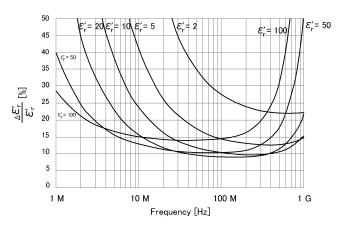
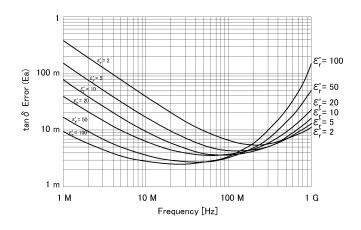
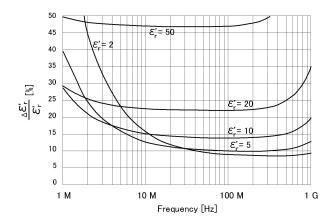
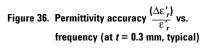


Figure 38. Permittivity accuracy  $\frac{(\Delta \varepsilon'_r)}{\varepsilon'_r}$  vs. frequency (at t = 3 mm, typical)







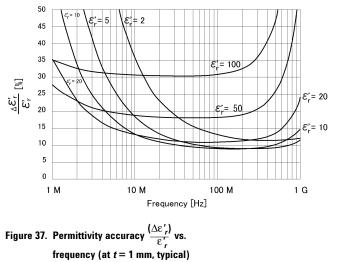


Figure 39. Dielectric loss tangent (tan $\delta$ ) accuracy vs. frequency (at t = 0.3 mm, typical)<sup>14</sup>

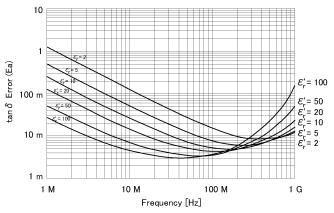


Figure 40. Dielectric loss tangent (tan $\delta$ ) accuracy vs. frequency (at t = 1 mm, typical)<sup>14</sup>

14. This graph shows only frequency dependence of  $E_a$  for simplification. The typical accuracy of tan $\delta$  is defined as  $E_a + E_b$ ; refer to "Typical permittivity measurement accuracy" on page 27.

## Examples of Calculated Permittivity Measurement

Accuracy (continued)

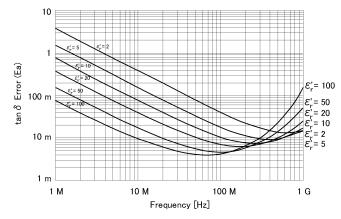


Figure 41. Dielectric loss tangent  $(tan\delta)$ accuracy vs. frequency (at t = 3 mm, typical)<sup>14</sup>

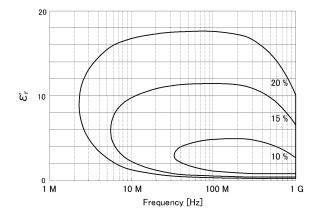


Figure 42. Permittivity ( $\epsilon'_r$ ) vs. frequency (at t = 0.3 mm, typical)

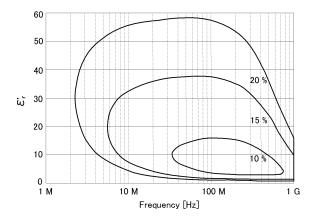


Figure 43. Permittivity  $(\epsilon'_r)$  vs. frequency (at t = 1 mm, typical)

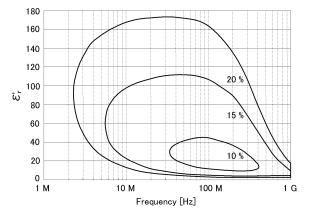
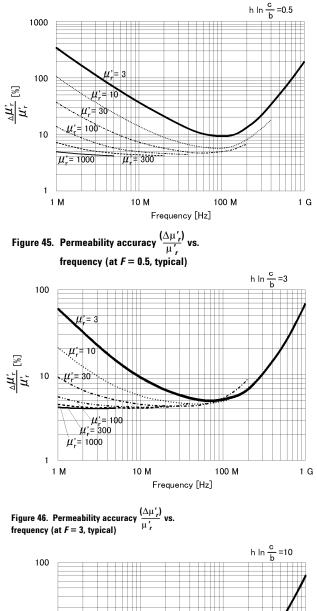
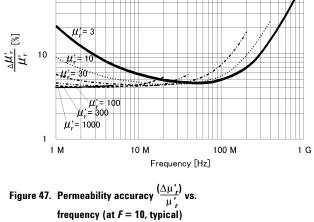


Figure 44. Permittivity ( $\epsilon'_r$ ) vs. frequency (at t = 3 mm, typical)

14. This graph shows only frequency dependence of  $E_a$  for simplification. The typical accuracy of tan $\delta$  is defined as  $E_a + E_b$ ; refer to "*Typical permittivity measurement accuracy*" on page 27.







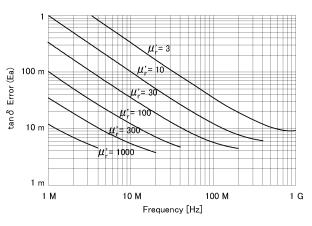


Figure 48. Permeability loss tangent (tan $\delta$ ) accuracy vs. Frequency (at F = 0.5, typical)<sup>15</sup>

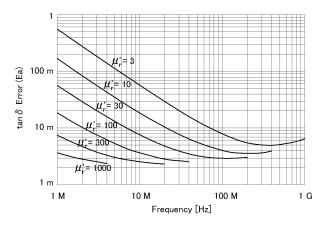


Figure 49. Permeability loss tangent (tan $\delta$ ) accuracy vs. Frequency (at F = 3, typical)<sup>15</sup>

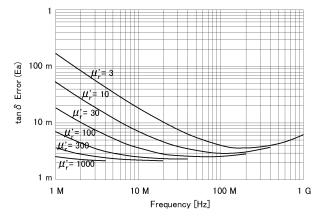


Figure 50. Permeability loss tangent (tan $\delta$ ) accuracy vs. Frequency (at F = 10, typical)<sup>15</sup>

15. This graph shows only frequency dependence of  $E_a$  for simplification. The typical accuracy of tan $\delta$  is defined as  $E_a + E_b$ ; refer to "Typical permeability measurement accuracy" on page 28.

## **Examples of Calculated Permeability Measurement**

Accuracy (continued)

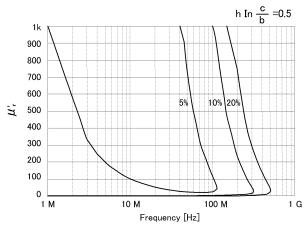


Figure 51. Permeability  $(\mu'_r)$  vs. frequency (at F = 0.5, typical)

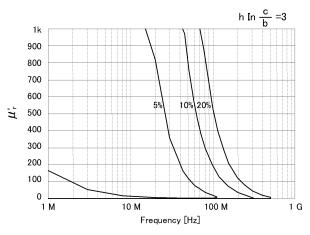
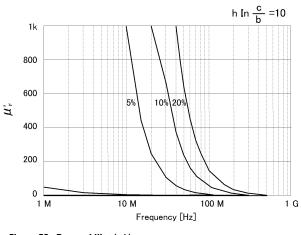
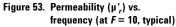


Figure 52. Permeability  $(\mu'_r)$  vs. frequency (at F = 3, typical)





## Typical Effects of Temperature Change on Permittivity Measurement Accuracy

When the temperature at the test port (7-mm connector) of the high temperature cable changes more than 5 °C from the calibration temperature, the typical permittivity measurement accuracy involving temperature dependence effects (errors) is applied. The typical permittivity accuracy is represented by the sum of error due to temperature coefficient  $(T_c)$ , hysteresis error  $(T_c \times \Delta T_{max})$  and the accuracy at 23 °C ± 5 °C.

Typical accuracy of permittivity parameters:

$$\begin{split} \boldsymbol{\varepsilon}_{r}^{'} & \text{accuracy} \ = \left(\frac{\Delta \boldsymbol{\varepsilon}^{'} \boldsymbol{\varepsilon}_{rm}}{\boldsymbol{\varepsilon}^{'} \boldsymbol{\varepsilon}_{rm}}\right) : \\ & \pm \left(E_{\boldsymbol{\varepsilon}} + E_{f} + E_{g}\right) \left[\%\right] \end{split}$$

Loss tangent accuracy of  $\dot{\epsilon}$  (=  $\Delta tan\delta$ ) :

$$\pm\,\frac{(E_{\epsilon}+E_{f}+E_{g}\,)}{100}$$

where,

$$E_{\epsilon}~$$
 = Permittivity measurement accuracy at 23 °C ± 5 °C

$$\begin{split} E_f &= T_c \times \Delta T \\ E_g &= T_c \times \Delta T_{max} \times 0.3 \\ Tc &= K_1 + K_2 + K_3 \end{split}$$

See Figure 54 through Figure 56 for the calculated value of  $T_{c}$  without temperature compensation

`

$$K_1 = 1 \times 10^{-6} \times (60 + 150 \times f)$$
  
 $K_2 = (-1)^{-6}$ 

$$3 \times 10^{-6} \times (1+10 \times f) \times \left(\frac{\hat{\epsilon}_{rm}}{t} \times \left|\frac{1}{1 - \left(\frac{f}{f_o}\right)^2}\right| + 10\right) \times f$$

 $K_{3} =$ 

$$5 \times 10^{-3} \times (0.3 + 3 \times f) \times \left( \frac{\varepsilon_{rm}}{t} \times \frac{1}{\left| 1 - \left( \frac{f}{f_o} \right)^2 \right|} + 10 \right) \times f$$

#### Typical accuracy of permittivity parameters (continued):

with temperature compensation

$$\begin{split} K_{1} &= 1 \times 10^{-6} \times (60 + 150 \times f) \\ K_{2} &= 1 \; \mathrm{MHz} \leq f < 500 \; \mathrm{MHz} \end{split}$$

$$3 \times 10^{-6} \times (1 + 10 \times f) \times \left(\frac{\varepsilon_{rm}}{t} \times \left|\frac{1}{1 - \left(\frac{f}{f_o}\right)^2}\right| + 10\right) \times f$$

500 MHz  $\leq f \leq 1~{\rm GHz}$ 

$$3 \times 10^{-6} \times (5 + 2 \times f) \times \left(\frac{\varepsilon_{rm}}{t} \times \left|\frac{1}{1 - \left(\frac{f}{f_o}\right)^2}\right| + 10\right) \times f$$

 $K_{3}$  = 1 MHz  $\leq f < 500$  MHz

$$\frac{1}{5 \times 10^{-3} \times (0.3 + 3 \times f) \times \left| \frac{\varepsilon_{rm}}{t} \times \frac{1}{\left| 1 - \left(\frac{f}{f_o}\right)^2 \right|} + 10 \right| \times f}$$

500 MHz  $\leq f \leq 1~{\rm GHz}$ 

$$5 \times 10^{-3} \times (1.5 + 0.6 \times f) \times \left(\frac{\varepsilon_{rm}}{t} \times \frac{1}{\left|1 - \left(\frac{f}{f_o}\right)^2\right|} + 10\right) \times f$$

1

*f* = Measurement frequency [GHz]

$$f_o = \frac{13}{\sqrt{\epsilon_r}} \text{ [GHz]}$$

*t* = Thickness of MUT (material under test) [mm]

 $\hat{\epsilon_{rm}}$  = Measured value of  $\hat{\epsilon_r}$ 

 $\Delta T$  = Difference of measurement temperature from calibration temperature

 $\Delta T_{max}$  = Maximum temperature change (°C) at test port from calibration temperature after the calibration is performed.

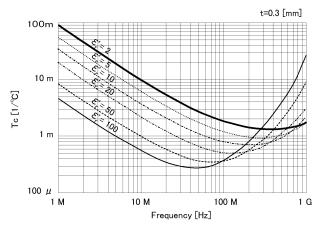
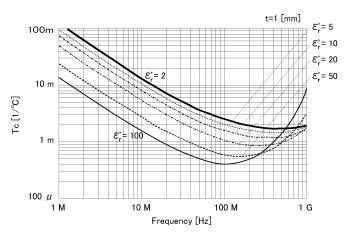
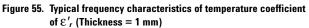


Figure 54. Typical frequency characteristics of temperature coefficient of  $\epsilon'_r$  (Thickness = 0.3 mm)





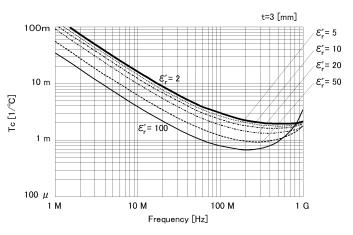


Figure 56. Typical frequency characteristics of temperature coefficient of  $\epsilon'_r$  (Thickness = 3 mm)

## Typical Effects of Temperature Change on Permeability Measurement Accuracy

When the temperature at the test port (7-mm connector) of the high temperature cable changes more than 5 °C from the calibration temperature, the typical permeability measurement accuracy involving temperature dependence effects (errors) is applied. The typical permeability accuracy is represented by the sum of error due to temperature coefficient  $(T_c)$ , hysteresis error  $(T_c \times \Delta T_{max})$  and the accuracy at 23 °C ±5 °C.

#### Typical accuracy of permeability parameters:

$$\mu_{r} \operatorname{accuracy} = \left( \frac{\Delta \mu_{rm}}{\mu_{rm}} \right) :$$

$$\pm (E_{\mu} + E_{h} + E_{i}) [\%]$$
Loss tangent accuracy of  $\mu_{r}$  (=  $\Delta \tan \delta$ ) :
$$\pm \frac{(E_{\mu} + E_{h} + E_{i})}{100}$$

where,

$$E_{\mu}$$
 = Permeability measurement accuracy  
at 23 °C ± 5 °C

$$E_h = T_c \times \Delta T$$

$$E_i$$
 =  $T_c \times \Delta T_{max} \times 0.3$ 

$$T_c \qquad = \quad K_4 + K_5 + K_6$$

See Figure 57 through Figure 59 for the calculated value of  $T_{c}$ 

without temperature compensation

$$K_4 = 1 \times 10^{-6} \times (60 + 150 \times f)$$

$$\begin{split} & K_5 &= \\ & 1 \times 10^{-2} \times (1 + 10 \times f) \times \frac{|1 - 0.01 \times \{F \times (\mu_{rm} - 1) + 10\} \times f^2|}{\{F \times (\mu_{rm} - 1) + 20\} \times f} \end{split}$$

$$K_6$$

$$2 \times 10^{-6} \times (0.3 + 3 \times f) \times \frac{\{F \times (\mathring{\mu_{rm}} - 1) + 20\} \times f}{|1 - 0.01 \times \{F \times (\mathring{\mu_{rm}} - 1) + 10\} \times f^2|}$$

with temperature compensation

=

$$\begin{array}{ll} K_4 & = & 1 \times 10^{-6} \times (60 + 150 \times f) \\ K_5 & = & \end{array}$$

$$1 \text{ MHz} \le f \le 500 \text{ MHz}$$

$$1 \times 10^{-2} \times (1 + 10 \times f) \times \frac{|1 - 0.01 \times \{F \times (\mu_{rm} - 1) + 10\} \times f^2|}{\{F \times (\mu_{rm} - 1) + 20\} \times f}$$

### 500 MHz $\leq f \leq 1~{\rm GHz}$

$$1 \times 10^{-2} \times (5+2 \times f) \times \frac{|1-0.01 \times \{F \times (\mathring{\mu_{rm}}-1)+10\} \times f^2|}{\{F \times (\mathring{\mu_{rm}}-1)+20\} \times f}$$

#### Typical accuracy of permeability parameters (continued):

$$\begin{split} K_6 &= 1 \ \mathrm{MHz} \leq f < 500 \ \mathrm{MHz} \\ & 2 \times 10^{-6} \times (0.3 + 3 \times f) \times \frac{\{F \times (\mu_{rm}^{'} - 1) + 20\} \times f}{|1 - 0.01 \times \{F \times (\mu_{rm}^{'} - 1) + 10\} \times f^2|} \end{split}$$

$$\begin{aligned} & 500 \text{ MHz} \le f \le 1 \text{ GHz} \\ & 2 \times 10^{-6} \times (1.5 + 0.6 \times f) \times \frac{\{F \times (\mu_{rm}^{'} - 1) + 20\} \times f}{|1 - 0.01 \times \{F \times (\mu_{rm}^{'} - 1) + 10\} \times f^{2}|} \end{aligned}$$

*f* = Measurement frequency [GHz]

$$F = h \ln \frac{c}{b} \, [mm]$$

- *h* = Height of MUT (material under test) [mm]
- *b* = Inner diameter of MUT [mm]
- c = Outer diameter of MUT [mm]
- $\mu'$  = Measured value of  $\mu'_r$
- $\Delta T$  = Difference of measurement temperature from calibration temperature
- $\Delta T_{max}$  = Maximum temperature change (°C) at test port from calibration temperature after the calibration is performed.

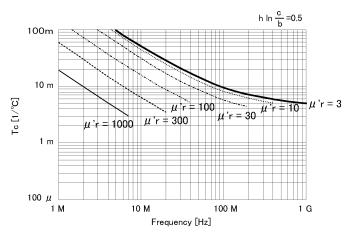


Figure 57. Typical frequency characteristics of temperature coefficient of  $\mu$  ' \_r (at F = 0.5)

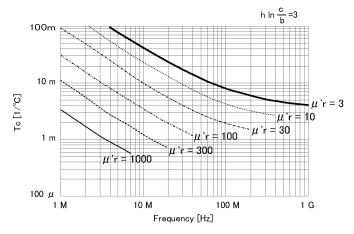


Figure 58. Typical frequency characteristics of temperature coefficient of  $\mu'_r$  (at F = 3)

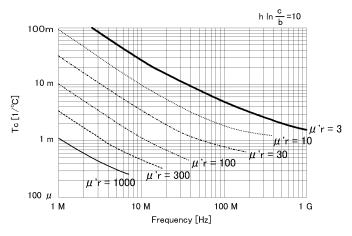


Figure 59. Typical frequency characteristics of temperature coefficient of  $\mu'_r$  (at F = 10)

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#### **Other Asia Pacific Countries:**

(tel) (65) 6375 8100 (fax) (65) 6755 0042 Email: tm\_ap@agilent.com Contacts revised: 9/17/04

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